

**Amendments to the Claims:**

This listing of claims will replace all prior versions, and listings, of claims in the application:

**Listing of Claims:**

1. (Currently Amended) A semiconductor laser device comprising:  
  
a base portion having a horizontal top surface;  
  
a heat sink portion that has a vertical element mount surface and is located above the top surface of the base portion;  
  
a semiconductor laser element that is fixed to the element mount surface; and  
  
a depression that is formed in the top surface of the base portion located immediately below the semiconductor laser element so as to receive part of the semiconductor laser element disposed therein,  
  
wherein the heat sink portion is fixed to the base portion in such a way that the element mount surface is located inward of an inner side surface of the depression, and that ~~a clearance is provided between a lower end portion of the element mount surface and a bottom surface of the depression~~ a lower end portion of the element mount surface and a bottom surface of the depression face each other with a space left therebetween.

2. (Original) The semiconductor laser device of claim 1,  
  
wherein the depression is formed within an area of a circle including, on a circumference thereof, a plurality of lead pins that feed a voltage to the semiconductor laser element.

3. (Original) The semiconductor laser device of claim 1,  
wherein the semiconductor laser element is fixed to the heat sink portion via a submount,  
part of which is disposed in the depression.

4. (Original) The semiconductor laser device of claim 1,  
wherein a length of the semiconductor laser element is longer than a height of the heat  
sink portion.

5. (Original) The semiconductor laser device of claim 1,  
wherein the base portion and the heat sink portion are formed as a single member.

6. (Currently Amended) The semiconductor laser device of claim 1,  
wherein the depression has a rough bottom surface that can prevent feedback light from  
being produced by diffusely reflect reflecting secondary laser light.

7. (Previously Presented) The semiconductor laser device of claim 1,  
wherein the depression has an inclined bottom surface.